
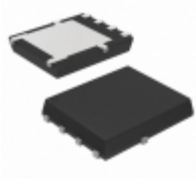
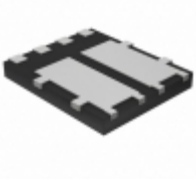
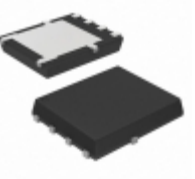
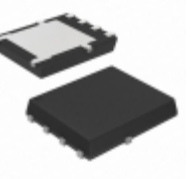
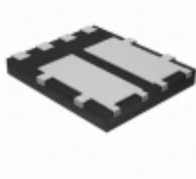
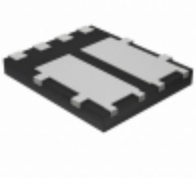
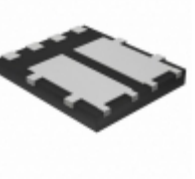
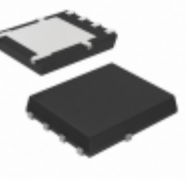
	<h2 style="color: red;">NVMFS4841NT1G</h2>
	<p>Hersteller-Teilenummer: NVMFS4841NT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 89A SO-8FL</p> <hr/> <p>Datenblätter:  NVMFS4841NT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS4841NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 89A SO-8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	7 mOhm @ 30A, 10V
Verlustleistung (max)	3.7W (Ta), 112W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1436pF @ 12V
Gate Charge (Qg) (Max) @ Vgs	17nC @ 4.5V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Ta)

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RFQ NVMFS4841NT1G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMFS4C01NT1G ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>	 <p>NVMFD5C674NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 42A SO8FL</p>	 <p>NVMFS4C01NT3G ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>	 <p>NVMFS4C01NWFT3G ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>
 <p>NVMFD5C680NLT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 26A SO8FL</p>	 <p>NVMFD5C672NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 49A SO8FL</p>	 <p>NVMFD5C674NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 60V 42A SO8FL</p>	 <p>NVMFS4C01NWFT1G ON Semiconductor MOSFET N-CH 30V 49A SO8FL</p>

Verwandtes Hot-Keyword

Mehr

NVMFS4841NT1G AMI Semiconductor / ON Semiconductor	NVMFS4841NT1G Datenblatt	NVMFS4841NT1G-Datenblätter	NVMFS4841NT1G PDF	AMI Semiconductor / ON Semiconductor NVMFS4841NT1G
NVMFS4841NT1G Electronic	NVMFS4841NT1G-Komponenten	NVMFS4841NT1G-Verteiler	NVMFS4841NT1G-Bild	NVMFS4841NT1G-Teil
NVMFS4841NT1G Preis	NVMFS4841NT1G Hersteller	NVMFS4841NT1G Bild	NVMFS4841NT1G Aktie	NVMFS4841NT1G Inventar
NVMFS4841NT1G Neu	NVMFS4841NT1G Original	NVMFS4841NT1G garantiert	NVMFS4841NT1G RFQ	NVMFS4841NT1G Online bestellen

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